Regarding the change of names mentioned in the document, such as Hitachi Electric and Hitachi XX, to Renesas Technology Corp.

The semiconductor operations of Mitsubishi Electric and Hitachi were transferred to Renesas Technology Corporation on April 1st 2003. These operations include microcomputer, logic, analog and discrete devices, and memory chips other than DRAMs (flash memory, SRAMs etc.) Accordingly, although Hitachi, Hitachi, Ltd., Hitachi Semiconductors, and other Hitachi brand names are mentioned in the document, these names have in fact all been changed to Renesas Technology Corp. Thank you for your understanding. Except for our corporate trademark, logo and corporate statement, no changes whatsoever have been made to the contents of the document, and these changes do not constitute any alteration to the contents of the document itself.

Renesas Technology Home Page: http://www.renesas.com

Renesas Technology Corp. Customer Support Dept. April 1, 2003



Cautions

Keep safety first in your circuit designs!

Renesas Technology Corporation puts the maximum effort into making semiconductor products better
and more reliable, but there is always the possibility that trouble may occur with them. Trouble with
semiconductors may lead to personal injury, fire or property damage.
Remember to give due consideration to safety when making your circuit designs, with appropriate
measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or
(iii) prevention against any malfunction or mishap.

Notes regarding these materials

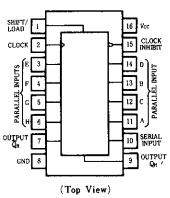
- 1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corporation product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corporation or a third party.
- 2. Renesas Technology Corporation assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
- 3. All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corporation or an authorized Renesas Technology Corporation product distributor for the latest product information before purchasing a product listed herein.
 - The information described here may contain technical inaccuracies or typographical errors. Renesas Technology Corporation assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.
 - Please also pay attention to information published by Renesas Technology Corporation by various means, including the Renesas Technology Corporation Semiconductor home page (http://www.renesas.com).
- 4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corporation assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.
- 5. Renesas Technology Corporation semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renesas Technology Corporation or an authorized Renesas Technology Corporation product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- 6. The prior written approval of Renesas Technology Corporation is necessary to reprint or reproduce in whole or in part these materials.
- 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination.
 - Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.
- 8. Please contact Renesas Technology Corporation for further details on these materials or the products contained therein.

HD74LS165A Parallel-Load 8-bit Shift Register

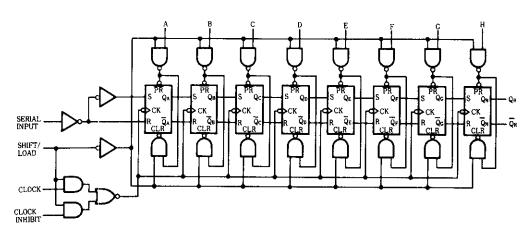
The LS165A are 8-bit serial shift registers that shift the data in the direction of Q_A toward Q_H when clocked. Parallel-in access to each stage is made available by eight individual direct data inputs that are enabled by a low level at the shift/load input. These registers also feature gated clock inputs and complementary outputs from the eighth bit. All inputs are diode-clamped to minimize transmission-line effects, thereby simplifying system design.

Clocking is accomplished through a 2-input positive-NOR gate, permitting one input to be used as a clock-inhibit function. Holding either of the clock inputs high inhibits clocking and holding either clock input low with the shift/load input high enables the other clock input. The clock-inhibit input should be changed to the high level only while the clock input is high. Parallel loading is inhibited as long as the shift/load input is high. Data at the parallel inputs are loaded directly into the register on a high-to-low transition of the shift/load input independently of the levels of the clock, clock inhibit, or serial inputs.

PIN ARRANGEMENT



IIIBLOCK DIAGRAM



IFUNCTION TABLE

-		INTERNAL		OVIEDVIE			
SHIFT/	CLOCK	CLOCK	SERIAL	PARALLEL	OUTPUTS		OUTPUT
LOAD	INHIBIT	CLUCK.	SEKIAL	АН	QA	Qв	Qн
L	X	Х	Х	ah	a	b	h
Н	L	L	Х	Х	Qao	QBo	Qно
Н	L	†	Н	Х	Н	QAn	QGn
Н	L	Ť	L	Х	L	Qan	QGn
Н	H	х	X	х	QAO	Qво	Qно

- Notes) 1. H; high level, L; low level, X; irrelevant
 - 2. t; transition from low to high level
 - 3. a ~ h; the level of steady-state input at inputs A to H respectively
 - QA0 ~ QH0; the level of QA to QH, respectively, before the indicated steady-state input conditions were established.
 - QAn ~ QGn; the level of QA to QG, respectively, before the most recent 4
 transition of the clock.

HD74LS165A

■RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	Unit
High level output current	Іон			400	μA
Low level output current	Io _L			8	mA
Clock frequency	feturk	0		25	MHz
Clock pulse width	tw (clock)	25	_	-	ns
Load pulse width	tw (load)	15		_	ns
Clock-enable Setup time	tsu	30		-	ns
Parallel-input Setup time	Lou	10	_		ns
Serial input setup time	teu	20		-	ns
Shift setup time	t.ru	45			ns
Hold time at only input	th	0		_	ns

ELECTRICAL CHARACTERISTICS ($Ta = -20 \sim +75$ °C)

Item		Symbol	Test Conditions		min	typ*	max	Unit
Input voltage		Viii			2.0			V
		VII.					0.8	V
Output voltage		Vin	$V_{CC} = 4.75 \text{V}$. $V_{IH} = 2 \text{V}$, $V_{IL} = 0.8 \text{V}$, $I_{OH} = -400 \mu \text{A}$		2.7			V
		.,	Vcc = 4,75V. Viн = 2V	$I_{OL} = 4 \text{mA}$			0.4	V
		V_{0I}	$V_{LL} = 0.8 \text{V}$	IoL = 8mA			0.5	V
Input current	Shift/Load		$V_{CC} = 5.25 \text{V}$ $V_t = 7 \text{V}$				0.3	mA
	Other inputs	II .					0.1	mA
High level input	nput Shift/Load					60	μA	
current Other inputs		hн	$V_{CC} = 5.25 \text{V} \qquad V_I = 2.7 \text{V}$				20	μΛ
Low level input	level input Shift/Load					1.2	mA	
current	Other inputs	In.	$V_{cc} = 5.25 V \qquad V_i = 0.4 V$			-	- 0.4	mA
Short-circuit output current		los	$V_{CC} = 5.25 \text{V}$		20		- 100	mA
Supply current**		I cc	$V_{CC} = 5.25 \text{V}$				36	mA
Input clamp voltage		Vik	$V_{CC} = 4.75 \text{V}, \ I_{IN} = -18 \text{mA}$				1.5	V

ESWITCHING CHARACTERISTICS ($V_{CC}=5V$, Ta=25°C)

Item	Symbol	Input	Output	Test Conditions	min	typ	max	Unit
Maximum Clock frequency	fmax				25	35		MHz
	tphl .	Load	Any	$C\iota = 15 \text{pF}$ $R\iota = 2 \text{k}\Omega$		21	35	ns
	₽LH					26	35	ns
	trнi.	Clock	Any		_	14	25	ns
D	tri.н					16	25	ns
Propagation Delay time	tрнL	н	Qн			13	25	ns
	tp1.H					24	30	ns
	tr⊥.H					19	30	ns
	tыr	Н	Qн		j	17	25	ns

 V_{CC} = 5V, Ta = 25°C • With the outputs open, clock inhibit and clock at 4.5V, and a clock pulse applied to the shift/load, I_{CC} is measured with the parallel inputs at 4.5V, than with the parallel inputs grounded.

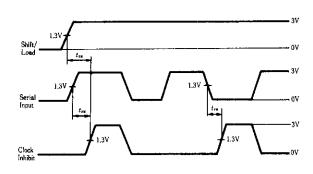
TESTING METHOD

Test Circuit

Load Circuit 1 Serial Input Shift/Load Input Testing Table P.G. Zout =500 ġ, Clock Q Same as Load Circuit 1

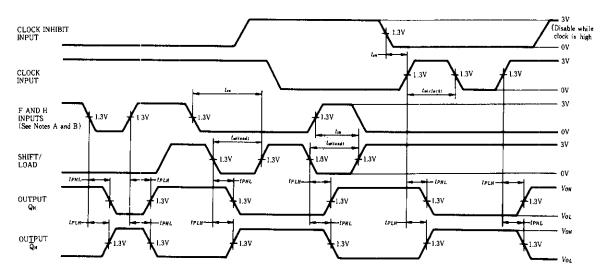
Notes) 1. C_L includes probe and jig capacitance. 2. All diodes are 1S2074 (f).

Waveform



- Notes) A. The eight data inputs and the clock-inhibit input are low. Results are monitored at output QH at tn+7.
 - B. The input pulse generators have the following characteristics: PRR < 1 MHz, duty cycle < 50%, $Z_{out} \approx 50\Omega$, $t_f \le 15$ ns, $t_f \le 6$ ns.

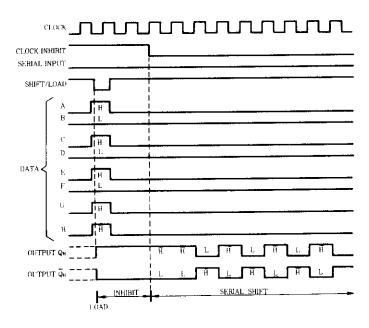
Waveform



Notes) A. The remaining six data inputs and the serial input are low.

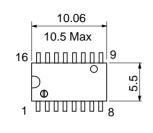
- B. Prior to test, high-level data is loaded into H input. C. The input pulse generators have the following characteristics: $PRR \le 1$ MHz, duty cycle $\le 50\% Z_{\text{out}} \approx 50\Omega$, $t_r \le 15$ ns, $t_f \le 6$ ns.

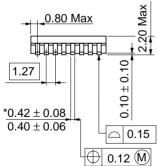
MTYPICAL SHIFT, LOAD AND INHIBIT SEQUENCES



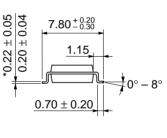
Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min $0.25^{+0.13}_{-0.05}$ 0.48 ± 0.10 2.54 ± 0.25 $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

Unit: mm





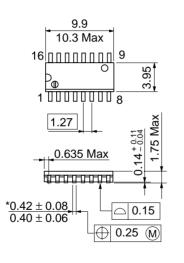


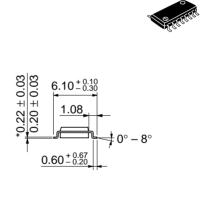


Hitachi Code	FP-16DA
JEDEC	_
EIAJ	Conforms
Weight (reference value)	0.24 g

*Dimension including the plating thickness
Base material dimension

Unit: mm





*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HTACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

NorthAmerica URL Europe

http://www.hitachi-eu.com/hel/ecg http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm

http:semiconductor.hitachi.com/

http://www.hitachi.co.jp/Sicd/indx.htm Japan

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218

Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.